NSN 5961-01-364-1224

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View Online at https://aerobasegroup.com/nsn/5961-01-364-1224 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Field effect **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -25.0 forward gate to source breakdown voltage and -1.0 gate to source cutoff voltage and -6.0 gate to source cutoff voltage **Current Rating Per Characteristic:** -150.00 microamperes reverse gate current with all other terminals short-circuit to source, junction-gate and 20.00 milliamperes zero-gate-voltage drain current and 60.00 milliamperes zero-gate-voltage drain current **Power Rating Per Characteristic:** 300.0 milliwatts on-state power dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: